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(54) **ORGANIC LIGHT EMITTING DIODE DISPLAY DEVICE AND METHOD OF DRIVING THE SAME**
 ANZEIGEVORRICHTUNG MIT ORGANISCHEN LICHTEMITTIERENDEN DIODEN UND VERFAHREN ZUR ANSTEUERUNG DAVON
 DISPOSITIF D’AFFICHAGE À DIODE ÉLECTROLUMINESCENTE ORGANIQUE ET SON PROCÉDÉ DE COMMANDE

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Description

BACKGROUND OF THE INVENTION

Field of the Invention

[0001] The present invention relates to an organic light emitting diode (OLED) display device. More particular, the present invention relates to an OLED display device capable of sensing and correcting a progressive bright point defect, and a method of driving the same.

Discussion of the Related Art

[0002] A liquid crystal display (LCD) using a liquid crystal, an organic light emitting diode (OLED) display device using an OLED, an electrophoretic display (EPD) using electrophoretic particles, etc. have been generally used as a flat panel display device that displays an image using digital data.

[0003] Among the above-mentioned devices, the OLED display device is a self-emissive device that allows an organic light emitting layer to emit light through recombination of an electron and a positive hole. The OLED display device has a high luminance and a low driving voltage and may be configured as an ultra-thin film. Thus, the OLED display device is expected to be used as a next generation display device.

[0004] Each of a plurality of pixels or sub-pixels included in the OLED display device has an OLED element that includes an organic light emitting layer between an anode and a cathode and a pixel circuit that independently drives the OLED element.

[0005] The pixel circuit includes a switching thin film transistor (TFT) that supplies a data voltage such that a storage capacitor is charged with a voltage corresponding to the data voltage, a driving TFT that controls a current based on the voltage with which the storage capacitor is charged and supplies the current to the OLED element, etc. The OLED element generates light in proportion to the current. The current supplied to the OLED element is affected by driving characteristics such as threshold voltage (V_{th}), mobility, etc. of the driving TFT.

[0006] However, the threshold voltage, the mobility, etc. of the driving TFT differ between sub-pixels for various reasons. For example, an initial threshold voltage, a mobility, etc. of the driving TFT differ between sub-pixels due to process variation, etc., and a difference occurs between sub-pixels due to deterioration of the driving TFT, etc. that occurs as a driving time passes. As a result, currents of the respective sub-pixels are non-uniform for the same data, and thus a problem of non-uniform luminance occurs. To solve this problem, the OLED display device uses an external compensation method of compensating for data by sensing the driving characteristics of the driving TFT.

[0007] For example, the external compensation method senses a voltage (or a current) indicating a driving

characteristic of each driving TFT, computes compensation values for compensating for variations of a threshold voltage and a mobility of the driving TFT based on the sensed value to store the compensation values in a memory or update values, and then compensates for data to be supplied to each sub-pixel using the stored compensation values.

[0008] US 2008/084365 A1 discloses an organic light emitting diode display device including a checking circuit, i.e. for detecting a short circuit between source signal lines, to identify and sort out defect devices in an early phase.

[0009] US 2013/050292 A1 discloses an organic light emitting diode display device including sensing of a pixel current and an appropriate compensation of the input data.

[0010] US2007/159742 A1 discloses an organic light emitting diode display device including an interruption circuit for interrupting a supply current to the light emitting element if the element is short-circuited.

[0011] The OLED display device has a problem of a minute short-circuit defect due to particles, etc. that enter during a manufacturing process. The minute short-circuit defect is not detected in an inspection process, etc. prior to product shipping. However, when a driving time passes after product shipping, a resistance component due to the particles gradually decreases. In this way, short-circuit is generated, which leads to a progressive bright point defect.

[0012] Therefore, while a short-circuit defect detected in the inspection process may be corrected to be darkened by being repaired, the progressive bright point defect, which is not detected in the inspection process and found with the lapse of a driving time due to the minute short-circuit defect, may neither be detected nor corrected.

SUMMARY OF THE INVENTION

[0013] Accordingly, the present invention has been conceived to solve the above-described problem, and a subject to be solved by the present invention relates to an organic light emitting diode (OLED) display device capable of sensing and correcting a progressive bright point defect and a method of driving the same.

[0014] To solve the above subject, an OLED display device according to the present invention includes the features of claim 1 and a method of driving an OLED display device according to the present invention includes the features of independent claim 5.

[0015] Advantageous embodiments of the invention are recited by the dependent claims.

BRIEF DESCRIPTION OF THE DRAWINGS

[0016] The accompanying drawings, which are included to provide a further understanding of the invention and are incorporated in and constitute a part of this applica-

tion, illustrate embodiment(s) of the invention and together with the description serve to explain the principle of the invention. In the drawings:

[0017] sensed threshold voltage is less than the minimum threshold voltage, and darken the sub-pixel sensed to have the normal bright point by supplying black data to the sub-pixel.

[0018] The bright point estimator may estimate and sense a sub-pixel expected to have the progressive bright point as a driving time passes due to a minute short-circuit resulting from particles between a supply line of a high-potential voltage and a gate node of the driving transistor.

[0019] A method of driving an OLED display device according to an embodiment of the present invention includes sensing a voltage corresponding to a leakage current according to an off-driving voltage of a driving transistor for driving a light emitting element in each sub-pixel, estimating a progressive bright point of a sub-pixel by comparing a value of the sensed voltage with a black data value, and darkening and correcting the sub-pixel expected to have the progressive bright point; wherein the sensing includes supplying from a data driver a black data voltage, converted from the black data value, and a reference voltage to first and second nodes, respectively, of the driving transistor of the sub-pixel to supply a difference voltage of the black data voltage and the reference voltage as the off-driving voltage to the driving transistor.

[0020] The sensing may include: allowing the leakage current according to the off-driving voltage of the driving transistor to flow to the light emitting element during a predetermined light emission period; and storing the leakage current of the driving transistor in a capacitor connected to a reference line to sense a voltage stored in the capacitor.

[0021] The estimating may include comparing the sensed voltage value with the black data value, and estimating the sub-pixel to have the progressive bright point when the sensed voltage value is greater than or equal to the black data value.

[0022] The storing may include supplying the black data voltage to the sub-pixel estimated to have the progressive bright point, and adjusting the reference voltage according to the sensed voltage to darken the sub-pixel.

[0023] The method may further include, before supplying the black data voltage and the reference voltage: sensing a threshold voltage of each driving transistor; comparing the sensed threshold voltage with a predetermined minimum threshold voltage to sense a normal bright point in which the sensed threshold voltage is less than the minimum threshold voltage; and darkening a sub-pixel sensed to have the normal bright point by supplying the black data voltage to the sub-pixel.

BRIEF DESCRIPTION OF THE DRAWINGS

[0024] The accompanying drawings, which are includ-

ed to provide a further understanding of the invention and are incorporated in and constitute a part of this application, illustrate embodiment(s) of the invention and together with the description serve to explain the principle of the invention. In the drawings:

FIG. 1 is an equivalent circuit diagram illustrating an example of a sub-pixel having a progressive bright point defect in an OLED display device according to the present invention;

FIG. 2 is a graph illustrating a change characteristic of voltage versus current due to a minute short-circuit defect of a driving transistor illustrated in FIG. 1;

FIG. 3 is an equivalent circuit diagram illustrating a portion of an OLED display device capable of estimating, sensing, and correcting a progressive bright point according to an embodiment of the present invention;

FIG. 4 is a diagram illustrating a driving waveform for sensing a leakage current in the OLED display device illustrated in FIG. 3;

FIGS. 5A, 5B, 5C and 5D are diagrams successively illustrating a leakage current sensing process of a sub-pixel illustrated in FIG. 3;

FIGS. 6A, 6B, 7A, 7B, 8A and 8B are diagrams illustrating simulation results obtained by sensing a leakage current according to a resistance value of a minute short-circuit of a driving transistor in an OLED display device according to an embodiment of the present invention;

FIG. 9 is a block diagram schematically illustrating an OLED display device according to an embodiment of the present invention; and

FIG. 10 is a flowchart illustrating, in stages, a method of estimating, sensing, and correcting a progressive bright point of an OLED display device according to an embodiment of the present invention.

DETAILED DESCRIPTION OF THE INVENTION

[0025] Prior to a description of a preferred embodiment of the present invention, a cause of a progressive bright point defect due to a minute short-circuit will be examined.

[0026] FIG. 1 is an equivalent circuit diagram illustrating an example of a sub-pixel expected to have a progressive bright point defect in an OLED display device according to the present invention, and FIG. 2 is a graph illustrating a change characteristic of a current with respect to a driving voltage of a driving transistor illustrated in FIG. 1.

[0027] A sub-pixel SP illustrated in FIG. 1 includes an OLED element and a pixel circuit that includes first and second switching transistors ST1 and ST2, a driving transistor DT, and a storage capacitor Cst to independently drive the OLED element.

[0028] The first switching transistor ST1 supplies a data voltage Vdata from a data line to a gate node N1 of the driving transistor DT according to a scan signal SC of one gate line.

[0029] The second switching transistor ST2 supplies a reference voltage Vref from a reference line RL to a source node N2 of the driving transistor DT according to a sensing control signal SE of another gate line. The second switching transistor ST2 is more frequently used as a path for outputting a current from the driving transistor DT to the reference line RL according to the sensing control signal SE in a sensing mode.

[0030] The storage capacitor Cst is charged with a difference voltage Vdata-Vref obtained by subtracting the reference voltage Vref supplied to the source node N2 through the second switching transistor ST2 from the data voltage Vdata supplied to the gate node N1 through the first switching transistor ST1 to supply the difference voltage as a driving voltage Vgs of the driving transistor DT.

[0031] The driving transistor DT controls a current supplied from a supply line of a high-potential voltage EVDD according to the driving voltage Vgs the storage capacitor Cst is charged with to supply a current Ids in proportion to the driving voltage Vgs to the OLED element, thereby allowing the OLED element to emit light.

[0032] Referring to FIG. 1, a minute short-circuit due to particles between the gate node N1 of the driving transistor DT and the supply line of the high-potential voltage EVDD is indicated by a resistance component R. Initially, the minute short-circuit due to the particles is not detected as a short-circuit defect in an inspection process, etc. since the resistance component R is great.

[0033] However, as the resistance component R of the minute short-circuit gradually decreases with the passage of a driving time, the gate node N1 of the driving transistor DT gradually increases by the high-potential voltage EVDD. Thus, as illustrated in FIG. 2, it can be understood that a leakage current is generated even when an off voltage (black data voltage) less than a threshold voltage is supplied as the driving voltage Vgs. When the OLED element emits light by the leakage current, a progressive bright point defect recognized as a bright point is generated.

[0034] To prevent the progressive bright point defect, the present invention proposes a scheme of estimating a progressive bright point due to the minute short-circuit defect by sensing the leakage current through long-term driving of the driving transistor DT, and darkening a sub-pixel estimated as the progressive bright point through voltage correction.

[0035] FIG. 3 is an equivalent circuit diagram illustrating a portion of an OLED display device capable of esti-

imating, sensing, and correcting a progressive bright point according to an embodiment of the present invention.

[0036] When compared to FIG. 1, FIG. 3 additionally illustrates a data driver 20 and a bright point estimator 50 connected to the data line DL and the reference line RL. Thus, description of components corresponding to duplicate elements between FIG. 1 and FIG. 3 will be omitted.

[0037] The data driver 20 supplies a black data voltage Vblack to each sub-pixel to sufficiently secure a light emitting time due to the leakage current of the driving transistor DT, and then senses and outputs a voltage corresponding to the leakage current of the driving transistor DT through the reference line RL.

[0038] The data driver 20 includes a data driving unit 22 that supplies the data voltage Vdata to the data line DL, a sensing unit 24 that senses a voltage corresponding to a current of the driving transistor DT through the reference line RL, and a switch SW that supplies the reference voltage Vref to the reference line RL.

[0039] The data driving unit 22 includes a digital-analog converter (hereinafter, referred to as a DAC) that converts input digital data into an analog data voltage Vdata and outputs the converted analog data voltage Vdata to the data line DL, etc.

[0040] The switch SW is turned ON only during a reference supply period (initialization period and light emission period) to supply the reference voltage Vref to the reference line RL.

[0041] The sensing unit 24 includes a sample and hold unit SH that samples and holds a voltage sensed through the reference line RL, an analog-digital converter (hereinafter, referred to as an ADC) that converts a sensing voltage from the SH into digital data and outputs the converted digital data to the bright point estimator 50, etc. The sample and hold unit SH includes a sampling switch SA and a capacitor Ch. The sampling switch SA samples a sensing voltage corresponding to the leakage current of the driving transistor DT through the reference line RL and stores the sensing voltage in the capacitor Ch, and the capacitor Ch supplies the stored sensing voltage to the ADC.

[0042] The bright point estimator 50 estimates whether a sub-pixel has a progressive bright point defect using a sensing value from the data driver 20 in a sensing mode, corrects the data voltage Vdata and the reference voltage Vref to be supplied to the sub-pixel such that a sub-pixel estimated to have the progressive bright point defect in a display mode is darkened, and supplies the corrected values to the data driver 20. A detailed description thereof will be provided below.

[0043] The OLED display device illustrated in FIG. 3 is in a leakage current sensing mode in which a leakage current of a sub-pixel is sensed as in FIGS. 4 and 5A-5D such that a progressive bright point due to a minute short-circuit is estimated.

[0044] FIG. 4 is a diagram illustrating a driving waveform of the OLED display device illustrated in FIG. 3 in

the leakage current sensing mode, and FIGS. 5A to 5D are diagrams successively illustrating a leakage current sensing process of the sub-pixel illustrated in FIG. 3.

[0045] The leakage current sensing mode includes an initialization period (FIG. 5A), a light emission period (FIG. 5B), and a sensing period (FIGS. 5C and 5D).

[0046] Referring to FIGS. 4 and 5A, in the initialization period, the data driver 20 (FIG. 3) supplies a black data voltage V_{black} to the data line DL, and supplies a reference voltage V_{ref} corresponding to an initialization voltage to the reference line RL. The first switching transistor ST1 is turned ON in response to a gate-on voltage V_{on} of the scan signal SC to supply the black data voltage V_{black} to the gate node N1 of the driving transistor DT, and the second switching transistor ST2 is turned ON in response to a gate-on voltage V_{on} of the sensing control signal SE to supply the reference voltage V_{ref} to the source node N2 of the driving transistor DT. In this way, the storage capacitor C_{st} is charged with a difference voltage $V_{black}-V_{ref}$ obtained by subtracting the reference voltage V_{ref} from the black data voltage V_{black} . The difference voltage $V_{black}-V_{ref}$ is less than a threshold voltage V_{th} of the driving transistor DT. In the initialization period illustrated in FIG. 4, a period in which the second switching transistor ST2 is turned ON by the sensing control signal SE may be longer than a period in which the first switching transistor ST1 is turned ON by the scan signal SC.

[0047] Referring to FIGS. 4 and 5B, in the light emission period, the first switching transistor ST1 is turned OFF in response to a gate-off voltage V_{off} of the scan signal SC, the second switching transistor ST2 is turned OFF in response to a gate-off voltage V_{off} of the sensing control signal SE, and the reference line RL maintains the reference voltage V_{ref} supplied from the data driver 20. The driving voltage V_{gs} ($=V_{black}-V_{ref}$) stored in the storage capacitor C_{st} is less than the threshold voltage V_{th} of the driving transistor DT. Thus, when the sub-pixel is in a normal state, the driving transistor DT is turned OFF, and the OLED element does not emit light. However, when the sub-pixel has a minute short-circuit defect due to particles between the supply line of the high-potential voltage EVDD and the gate node N1 of the driving transistor DT, the resistance component R of the minute short-circuit gradually decreases over time during the emission period. As a result, a voltage of the gate node N1 of the driving transistor DT increases due to the high-potential voltage EVDD, which leads to increase in the driving voltage V_{gs} of the driving transistor DT. In this way, the leakage current increases and thus the OLED element emit lights. The light emission period is set to a sufficiently long period which is longer than or equal to 50 msec in order to sense the leakage current due to the minute short-circuit.

[0048] Referring to FIGS. 4 and 5C, in the sensing period, the switch SW that supplies the reference voltage V_{ref} from the data driver 20 (FIG. 3) is turned OFF in response to the gate-off voltage V_{off} , and the reference

line RL floats. The second switching transistor ST2 is turned ON in response to the gate-on voltage V_{on} of the sensing control signal SE to supply the leakage current of the driving transistor DT to the reference line RL. In this way, a parasitic capacitor C_{ref} of the reference line RL is charged with a sensing voltage corresponding to the leakage current of the driving transistor DT, that is, a voltage of the source node N2 of the driving transistor DT.

[0049] Referring to FIGS. 4 and 5D, in the sampling period corresponding to a latter half of the sensing period, in response to the sampling switch SA of the data driver 20 illustrated in FIG. 3 being turned ON by the gate-on voltage V_{on} , the SH samples and holds the sensing voltage stored in the reference line RL and supplies the stored sensing voltage to the ADC, and the ADC converts the sensing voltage into a digital sensing value and supplies the digital sensing value to the bright point estimator 50.

[0050] The bright point estimator 50 illustrated in FIG. 3 compares the sensing value from the data driver 20 with the black data value supplied to the data driver 20. The bright point estimator 50 estimates the sub-pixel to have a progressive bright point defect when the sensing value is greater than or equal to the black data value, and estimates the sub-pixel to be a normal sub-pixel when the sensing value is less than the black data value.

[0051] The bright point estimator 50 darkens the sub-pixel estimated to have the progressive bright point defect in the display mode by correcting data and a reference voltage V_{ref1} to be supplied to the sub-pixel.

[0052] Specifically, the bright point estimator 50 corrects data of the sub-pixel estimated to have the progressive bright point defect to black data and supplies the black data to the data driver 20 such that the data driver 20 allows the black data voltage V_{black} to be supplied to the sub-pixel. Further, the bright point estimator 50 corrects the reference voltage V_{ref} to be supplied to the sub-pixel estimated to have the progressive bright point defect to a high value such that a corrected reference voltage V_{ref} is supplied to the sub-pixel through the data driver 20. The bright point estimator 50 may increase the reference voltage V_{ref} according to the sensing value.

[0053] In this way, in the display mode, a driving voltage V_{gs} ($=V_{black}-V_{ref} < V_{th}$) less than the threshold voltage V_{th} is supplied to the driving transistor DT of the sub-pixel at all times. Thus, the driving transistor DT is turned OFF, thereby darkening the sub-pixel. In addition, even when a voltage of the gate node N1 of the driving transistor DT increases as the resistance component R of the minute short-circuit gradually decreases, the driving voltage V_{gs} ($=V_{black}-V_{ref} < V_{th}$) less than the threshold voltage V_{th} is supplied to the driving transistor DT of the sub-pixel at all times due to the corrected reference voltage V_{ref} , and thus the driving transistor DT is turned OFF. In this way, the sub-pixel maintains a darkened state.

[0054] Therefore, the OLED display device according

to the present invention may estimate a progressive bright point resulting from a minute short-circuit defect by sensing a leakage current through a long-term driving of the driving transistor DT, and darken a sub-pixel estimated to have the progressive bright point, thereby preventing a progressive bright point defect.

[0055] FIGS. 6A, 6B, 7A, 7B, 8A and 8B are diagrams illustrating simulation results obtained by sensing a leakage current of a driving transistor DT in an OLED display device according to an embodiment of the present invention.

[0056] When a resistance R of the minute short-circuit illustrated in FIG. 3 is $10\text{G}\Omega$, FIG. 6A illustrates a result of sensing a voltage of the gate node N1 of the driving transistor DT, a voltage of the source node N2, a voltage of the reference line RL, and a current Ioled of the OLED element, and FIG. 6B illustrates a change characteristic of a current with respect to the driving voltage Vgs of the driving transistor DT.

[0057] Referring to FIG. 6A, it can be understood that, in a light emission period, the voltage of the gate node N1 of the driving transistor DT increases due to the component R of the minute short-circuit, and the voltage of the source node N2 and the OLED current Ioled increase due to the leakage current of the driving transistor DT resulting from increase in the voltage of the gate node N1, and thus the OLED element emits light in an abnormal manner. In addition, it can be understood that, in a sensing period after the light emission period, the voltage of the reference line RL increases according to the voltage of the source node N2 increased by the leakage current of the driving transistor DT. Therefore, it is possible to sense a voltage corresponding to the leakage current of the driving transistor DT through the reference line RL.

[0058] Referring to FIG. 6B, it can be understood that a sub-pixel having a minute short-circuit resistance R of $10\text{G}\Omega$ due to particles has a progressive bright point defect since a leakage current of a driving transistor DT greatly increases beyond a permitted range in an off region in which a driving voltage Vgs is less than a threshold voltage.

[0059] When a resistance R of the minute short-circuit illustrated in FIG. 3 is $100\text{G}\Omega$, which is ten times that of FIGS. 6A and 6B, FIG. 7A illustrates a result of sensing a voltage of the gate node N1 of the driving transistor DT, a voltage of the source node N2, a voltage of the reference line RL, and a current Ioled of the OLED element, and FIG. 7B illustrates a change characteristic of a current with respect to the driving voltage Vgs of the driving transistor DT.

[0060] Referring to FIG. 7A, it can be understood that, in a light emission period, the voltage of the gate node N1 of the driving transistor DT gradually increases due to the component R of the minute short-circuit, and the voltage of the source node N2 and the OLED current Ioled gradually increase due to the leakage current of the driving transistor DT resulting from the increase in the voltage of the gate node N1, and thus the OLED element

emits light in an abnormal manner. In addition, it can be understood that, in a sensing period after the light emission period, the voltage of the reference line RL increases according to the voltage of the source node N2 increased by the leakage current of the driving transistor DT. Therefore, it is possible to sense a voltage corresponding to the leakage current of the driving transistor DT through the reference line RL.

[0061] Referring to FIG. 7B, it can be understood that a sub-pixel having a minute short-circuit resistance R of $100\text{G}\Omega$ due to particles has a progressive bright point defect since a leakage current of a driving transistor DT greatly increases beyond a permitted range in an off region.

[0062] When a resistance R of the minute short-circuit illustrated in FIG. 3 is $1000\text{G}\Omega$, which is ten times that of FIGS. 7A and 7B, FIG. 8A illustrates a result of sensing a voltage of the gate node N1 of the driving transistor DT, a voltage of the source node N2, a voltage of the reference line RL, and a current Ioled of the OLED element, and FIG. 8B illustrates a change characteristic of a current with respect to the driving voltage Vgs of the driving transistor DT.

[0063] Referring to FIG. 8A, if the resistance component R is $1000\text{G}\Omega$, which is a large value, it can be understood that the voltage of the gate node N1 of the driving transistor DT, the voltage of the source node N2, the voltage of the reference line RL, and the OLED current Ioled do not significantly increase even when a driving time passes.

[0064] Referring to FIG. 8B, it can be understood that a sub-pixel having a great resistance R of $1000\text{G}\Omega$ is in a normal state in which a leakage current in an off region of a driving transistor DT is within a permitted range.

[0065] FIG. 9 schematically illustrates an OLED display device according to an embodiment of the present invention.

[0066] The OLED display device illustrated in FIG. 9 includes a timing controller 10 having a control signal generator 100 and an image processor 200, a memory M, a data driver 20, a gate driver 30, and a display panel 40. Here, the image processor 200 and the data driver 20 may be expressed as a data processor.

[0067] The image processor 200 may be incorporated in the timing controller 10 as illustrated in FIG. 9 and configured as one integrated circuit (IC), or configured as a separate IC by being separated from the timing controller 10 although not illustrated. In this case, the timing controller 10 may be connected between the image processor 200 and the data driver 20. Hereinafter, a description will be given of a case in which the timing controller 10 includes the image processor 200 as an example.

[0068] The memory M stores compensation information configured according to a characteristic of each sub-pixel for a uniform current of each sub-pixel. The compensation information includes a threshold voltage compensation value for compensating for a threshold voltage Vth of a driving transistor DT of each sub-pixel and a

mobility compensation value for compensating for a mobility variation of a driving transistor DT. The compensation information is configured in advance based on a sensing value which is obtained by sensing a threshold voltage and a mobility corresponding to driving characteristics of each sub-pixel before product shipping and stored in the memory M. After product shipping, the compensation information stored in the memory M is updated by sensing a characteristic of each sub-pixel again through a sensing mode in each desired driving time. The compensation information stored in the memory M may be updated by executing the sensing mode in each desired time corresponding to at least one of a boot time when power is turned ON, an ending time when power is turned OFF, a blanking period of each frame, etc.

[0069] For example, mobility is greatly affected by temperature, light, etc. which are external environment conditions, and thus may be sensed in each period corresponding to at least one of the boot time when power is turned ON and the blanking period of each frame such that the mobility compensation value stored in the memory M may be updated. The threshold voltage may be sensed in each period corresponding to at least one of the blanking period of each frame and ending time when power is turned OFF such that the threshold voltage compensation value stored in the memory M may be updated.

[0070] In the timing controller 10, the control signal generator 100 generates a data control signal and a gate control signal that control driving time of the data driver 20 and the gate driver 30 using a plurality of timing signals input to an external system (not illustrated), and outputs the generated signals to the data driver 20 and the gate driver 30. For example, the control signal generator 100 generates and outputs a plurality of data control signals including a source start pulse, a source shift clock, a source output enable signal, etc. that control driving timing of the data driver 20 and a plurality of gate control signals including a gate start pulse, a gate shift clock, etc. that control driving timing of the gate driver 30 using a plurality of timing signals such as a clock signal, a data enable signal, a horizontal synchronization signal, a vertical synchronization signal, etc. from the external system.

[0071] In the timing controller 10, the image processor 200 compensates for image data input from the external system using the compensation information of the memory M, and outputs the compensated data to the data driver 20. The image processor 200 processes sensing information of each sub-pixel sensed through the data driver 20 according to a predetermined operation to convert the sensing information into compensation information, and updates the compensation information of the memory M.

[0072] In addition, the image processor 200 determines a peak luminance according to an image of each frame using input image data and calculates a total current. In addition, the image processor 200 determines a high-potential voltage according to the peak luminance

and the total current and supplies the determined high-potential voltage to the data driver 20. In this way, power consumption is reduced.

[0073] In addition, in response to R/G/B data being input as image data from the external system, the image processor 200 may convert the R/G/B data into R'/G'/B'/W data through a predetermined operation and use the converted data for the above-described image processing. For example, the image processor 200 may generate a minimum gray level (or a common gray level) of the R/G/B data as W data according to a predetermined operation, and generates remaining R'/G'/B' data by subtracting each of the W data and the R/G/B data.

[0074] In addition, the image processor 200 may compare a threshold voltage of a driving transistor DT sensed from each sub-pixel in a desired sensing mode with a minimum threshold voltage to sense a normal bright point defect in which the sensed threshold value is less than the minimum threshold voltage, and darken a sub-pixel sensed to have the normal bright point defect by supplying black data in the display mode.

[0075] In particular, the image processor 200 may include the bright point estimator 50 illustrated in FIG. 3 to estimate a progressive bright point due to a minute short-circuit by sensing a leakage current of a driving transistor DT of each sub-pixel in a desired sensing mode, and darken a sub-pixel estimated as the progressive bright point by supplying black data and correcting a reference voltage in a display mode, thereby preventing a progressive bright point defect.

[0076] For example, normal bright point defect sensing and progressive bright point defect estimation and sensing of the image processor 200 may be executed in a sensing mode of a power-off state in which a threshold voltage of each driving transistor DT is sensed and updated. However, the present invention is not limited thereto.

[0077] The data driver 20 converts data supplied from the timing controller 10 into an analog data signal and supplies the converted signal to the display panel 40 using a data control signal supplied from the timing controller 10 in the display mode and the sensing mode. The data driver 20 converts digital data into an analog data voltage using a gamma voltage set from an integrated gamma voltage generator (not illustrated).

[0078] In addition, the data driver 20 converts a digital high-potential voltage supplied from a current controller 210 of the timing controller 10 into an analog high-potential voltage in the display mode and the sensing mode. Alternatively, the data driver 20 adjusts an analog high-potential voltage according to a digital high-potential voltage. Then, the data driver 20 supplies the voltage to the display panel 40. The gamma voltage generator divides the analog high-potential voltage through a resistor string to generate a gamma voltage set including a plurality of gamma voltages.

[0079] In addition, the data driver 20 converts a voltage (or a current) sensed through a reference line RL from

each sub-pixel of the display panel 40 in the sensing mode into a digital sensing value and supplies the converted value to the timing controller 10.

[0080] The data driver 20 is configured as one data drive IC and mounted on a circuit film such as a tape carrier package (TCP), a chip on film (COF), a flexible print circuit (FPC), etc. The data driver 20 may be attached to the display panel 40 using tape automated bonding (TAB) or mounted on a non-display region of the display panel 40 using a chip on glass (COG) scheme.

[0081] The gate driver 30 drives a plurality of gate lines of the display panel 40 using a gate control signal supplied from the timing controller 10. The gate driver 30 supplies a scan pulse of a gate-on voltage to each gate line in a scan period and supplies a gate-off voltage in a remaining period using the gate control signal. The gate control signal may be supplied to the gate driver 30 directly from the timing controller 10 or from the timing controller 10 via the data driver 20.

[0082] The gate driver 30 may be configured as at least one gate drive ID. The gate driver 30 may be mounted on a circuit film such as a TCP, a COF, an FPC, etc. and attached to the display panel 40 using TAB. Alternatively, the gate driver 30 may be mounted on a non-display region of the display panel 40 using the COG scheme. On the other hand, the gate driver 30 may be formed on a non-display region of a TFT substrate together with a TFT array which is formed in a pixel array, thereby being formed as a gate in panel (GIP) in which the gate driver 30 is incorporated in the display panel 40.

[0083] The display panel 40 includes a pixel array in a matrix form. Each pixel of the pixel array includes R/W/B/G sub-pixels. Alternatively, each pixel may include R/G/B sub-pixels.

[0084] FIG. 10 is a flowchart illustrating, in stages, a method of estimating, sensing, and correcting a progressive bright point of an OLED display device according to an embodiment of the present invention.

[0085] In step S2, the data driver 20 converts data for sensing supplied from the image processor 200 into an analog signal and supplies the converted signal to each sub-pixel of the display panel 40, and the image processor 200 senses a threshold voltage V_{th} of each sub-pixel through the data driver 20.

[0086] In step S4, the image processor 200 senses a normal bright point defect by comparing the sensed threshold voltage V_{th} of each sub-pixel with a predetermined minimum threshold voltage. The image processor 200 determines a sub-pixel to have the normal bright point defect when a sensed threshold voltage V_{th} thereof is less than the minimum threshold voltage, and proceeds to step S6 to darken the sub-pixel by supplying black data to the sub-pixel.

[0087] The image processor 200 determines a sub-pixel to be normal when a sensed threshold voltage V_{th} thereof is greater than or equal to the minimum threshold voltage, and proceeds to step S8 to normally drive normal sub-pixels.

[0088] In step S10, the data driver 20 converts the black data supplied from the image processor 200 into a black data voltage, supplies the converted voltage to each sub-pixel of the display panel 40, and senses a voltage corresponding to a leakage current of a driving transistor DT through a reference line RL after a sufficient light emission period. The image processor 200 estimates whether a progressive bright point defect is included by comparing the sensed value from the data driver 20 with the black data. When the sensed value is greater than or equal to the black data, the image processor 200 determines that the progressive bright point defect is included and proceeds to step S12 to supply the black data to the sub-pixel and darkens the sub-pixel by increasing a reference voltage V_{ref} according to the sensed value. As the sensed value increases, the reference voltage V_{ref} increases. Therefore, even when a minute short-circuit is generated in the driving transistor DT, a driving voltage V_{gs} of the driving transistor DT is less than the threshold voltage V_{th} , and thus the sub-pixel is darkened.

[0089] When the sensed value is less than the black data, the image processor 200 determines that the sub-pixel is normal and proceeds to step S14 to normally drive normal sub-pixels.

[0090] As described in the foregoing, an OLED display device and a method of driving the same according to the present invention may estimate and sense a sub-pixel expected to have a progressive bright point defect as a driving time passes due to a minute short-circuit by sensing a leakage current of a driving transistor DT for black data.

[0091] In addition, an OLED display device and a method of driving the same according to the present invention may darken a sub-pixel sensed and estimated to have a progressive bright point defect by correcting a gate-source voltage V_{gs} of a driving transistor DT to be less than a threshold voltage V_{th} using a black data voltage and a relatively high reference voltage.

[0092] In this way, an OLED display device and a method of driving the same according to the present invention may enhance image quality and increase lifespan by estimating and sensing a progressive bright point defect to correct the defect.

[0093] Thus, it is intended that the present invention covers the modifications and variations of this invention provided they come within the scope of the appended claims.

Claims

1. An organic light emitting diode (OLED) display device comprising:
 - a plurality of sub pixels (SP), each comprising:
 - a light emitting element (OLED) and a driving transistor (DT) for driving the light emit-

ting element (OLED),
 a first switching transistor (ST1) connected
 between a data line (DL) and a first node
 (N1) of the driving transistor (DT), and
 a second switching transistor (ST2) con-
 nected between a reference line (RL) and
 a second node (N2) of the driving transistor
 (DT), the reference line (RL) having a ca-
 pacitor (Cref) connected thereto; and

a data driver (20) configured to supply a data
 voltage (Vdata) through the data line (DL) and
 a reference voltage (Vref) through the reference
 line (RL) to each sub-pixel (SP) of the plurality
 of sub pixels (SP);
 wherein, in a sensing mode:

the data driver (20) is configured to supply
 a black data voltage (Vblack), converted
 from the black data value, through the first
 switching transistor (ST1) to the first node
 (N1) and a reference voltage (Vref) through
 the second switching transistor (ST2) to the
 second node (N2) to thus supply a differ-
 ence voltage of the black data voltage
 (Vblack) and the reference voltage (Vref) as
 an off-driving voltage to the driving transis-
 tor (DT); and
 the capacitor (Cref) connected to the refer-
 ence line is configured to store a voltage
 according to the leakage current of the driv-
 ing transistor (DT) according to the off-driv-
 ing voltage after a predetermined light emis-
 sion period of the sensing mode during
 which the leakage current, according to the
 off-driving voltage of the transistor (DT),
 flows to the light emitting element (OLED);
 and
 wherein the data driver (20), in the sensing
 mode, is further configured to sense in the
 sensing mode through the reference line
 (RL) a voltage stored in a capacitor (Cref),
 which is connected to the reference line
 (RL);

characterised in that the organic light
 emitting diode display device further com-
 prises
 a bright point estimator (50) configured to:

estimate whether a sub-pixel (SP) has
 a progressive bright point defect by
 comparing the value of said voltage
 sensed through the data driver (20) with
 a reference value;
 correct
 the data voltage (Vdata) and the refer-
 ence voltage (Vref) to be supplied to
 the sub-pixel (SP) estimated to have

the progressive bright point defect such
 that said sub-pixel (SP) is darkened in
 a display mode; and to
 supply the corrected values for the data
 voltage (Vdata) and the reference volt-
 age (Vref) to the data driver (20) where-
 in, in a display mode, the driving voltage
 (Vref) for the driving transistor (DT) of
 the sub-pixel (SP) estimated to have
 the progressive bright point defect is
 configured to be less than a threshold
 voltage of said driving transistor (DT).

2. The OLED display device according to claim 1,
 wherein the bright point estimator (50) is configured
 to compare the sensed voltage value with the black
 data value, to estimate the sub-pixel (SP) to have
 the progressive bright point defect when the sensed
 voltage value is greater than or equal to the black
 data value, to allow the black data voltage (Vblack)
 to be supplied to the sub-pixel (SP) estimated to have
 the progressive bright point, and to darken the sub-
 pixel (SP) by increasing the reference voltage (Vref)
 according to the sensed voltage value.
3. The OLED display device according to claim 1, fur-
 ther comprising
 an image processor (200) including the bright point
 estimator (50),
 wherein the image processor (200) is configured to
 sense a threshold voltage of the driving transistor
 (DT) through the data driver (20), to compare the
 sensed threshold voltage with a predetermined min-
 imum threshold voltage to sense a normal bright
 point defect in which the sensed threshold voltage
 is less than the minimum threshold voltage, and
 darkens the sub-pixel (SP) sensed to have the nor-
 mal bright point defect by supplying black data to the
 sub-pixel (SP).
4. The OLED display device according to claim 3,
 wherein the bright point estimator (50) is configured
 to estimate and sense a sub-pixel (SP) expected to
 have the progressive bright point defect as a driving
 time passes due to a minute short-circuit resulting
 from particles between a supply line of a high-poten-
 tial voltage and a gate node (N1) of the driving tran-
 sistor (DT).
5. A method of driving an OLED display device com-
 prising:

supplying from a data driver (20) a black data
 voltage (Vblack), converted from the black data
 value, on a data line (DL) through a first switch-
 ing transistor (ST1) to a first node (N1) of a driv-
 ing transistor (DT) of a sub-pixel (SP), and a
 reference voltage (Vref) on a reference line (RL)

through a second switching transistor (ST2) to a second node of the driving transistor (DT) of the sub-pixel (SP) thus supplying a difference voltage of the black data (Vblack) and the reference voltage (Vref) as an off-driving voltage to the driving transistor (DT) of the sub-pixel (SP), allowing a leakage current according to the off-driving voltage of the driving transistor (DT) to flow to the light emitting element during a predetermined light emission period;

storing a voltage corresponding to the leakage current according to the off-driving voltage of the driving transistor (DT) in a capacitor (Cref) connected to the reference line (RL), and sensing the voltage stored in the capacitor (Cref) through the reference line (RL);

estimating whether a sub-pixel (SP) has a progressive bright point defect by comparing a value of the sensed voltage with a black data value; and

correcting the data voltage (Vdata) and the reference voltage (Vref) to be supplied to the sub-pixel (SP) estimated to have the progressive bright point defect such that the sub-pixel (SP) is darkened in a display mode, wherein the driving voltage for the driving transistor (DT) of the sub-pixel (SP) is configured to be less than a threshold voltage of the driving transistor (DT).

6. The method according to claim 5, wherein the estimating comprises comparing the sensed voltage value with the black data value, and estimating the sub-pixel (SP) to have the progressive bright point defect when the sensed voltage value is greater than or equal to the black data value.

7. The method according to claim 6, wherein the storing comprises supplying the black data voltage (Vblack) to the sub-pixel (SP) estimated to have the progressive bright point defect, and adjusting the reference voltage (Vref) according to the sensed voltage to darken the sub-pixel (SP).

8. The method according to claim 7, further comprising, before supplying the black data voltage (Vblack) and the reference voltage (Vref):

sensing a threshold voltage of each driving transistor (DT);

comparing the sensed threshold voltage with a predetermined minimum threshold voltage to sense a normal bright point defect in which the sensed threshold voltage is less than the minimum threshold voltage; and

darkening a sub-pixel (SP) sensed to have the normal bright point by supplying the black data voltage (Vblack) to the sub-pixel (SP).

Patentansprüche

1. Organische Leuchtdioden-(OLED)-Anzeigeeinrichtung, umfassend:

eine Mehrzahl von Sub-Pixeln (SP), die jeweils umfassen:

ein lichtemittierendes Element (OLED) und einen Ansteuertransistor (DT) zum Ansteuern des lichtemittierenden Elements (OLED),

einen ersten Schalttransistor (ST1), der zwischen eine Datenleitung (DL) und einen ersten Knoten (N1) des Treibertransistors (DT) geschaltet ist, und

einen zweiten Schalttransistor (ST2), der zwischen eine Referenzleitung (RL) und einen zweiten Knoten (N2) des Treibertransistors (DT) geschaltet ist, wobei an die Referenzleitung (RL) ein Kondensator (Cref) angeschlossen ist; und

einen Datentreiber (20), der konfiguriert ist, um jedem Sub-Pixel (SP) der Mehrzahl von Sub-Pixeln (SP) eine Datenspannung (Vdata) über die Datenleitung (DL) und eine Referenzspannung (Vref) über die Referenzleitung (RL) zuzuführen;

wobei in einem Abtastmodus:

der Datentreiber (20) konfiguriert ist, um eine Schwarzdaten-Spannung (Vblack), die aus dem Schwarzdaten-Wert konvertiert wurde, über den ersten Schalttransistor (ST1) an den ersten Knoten (N1) und eine Referenzspannung (Vref) über den zweiten Schalttransistors (ST2) an den zweiten Knoten (N2) zu liefern, um somit eine Differenzspannung aus der Schwarzdaten-Spannung (Vblack) und der Referenzspannung (Vref) als Sperrspannung zum Ansteuertransistor (DT) zu liefern; und

der mit der Referenzleitung verbundene Kondensator (Cref) konfiguriert ist, um eine Spannung entsprechend dem Leckstrom des Ansteuertransistors (DT) entsprechend der Sperrspannung nach einer vorgegebenen Lichtemissionsperiode des Abtastmodus zu speichern, während welcher der Leckstrom entsprechend der Sperrspannung des Treibertransistors (DT) zum lichtemittierenden Element (OLED) fließt; und

wobei der Datentreiber (20) im Abtastmodus ferner konfiguriert ist, um im Abtastmodus über die Referenzleitung (RL) eine in einem mit der Referenzleitung (RL) verbundenen Kondensator (Cref) gespeicherte

Spannung abzutasten;

dadurch gekennzeichnet, dass die organische Leuchtdioden-Anzeigeeinrichtung weiterhin umfasst, einen Hellpunktschätzer (50), der konfiguriert ist, zum:

Schätzen, ob ein Sub-Pixel (SP) einen progressiven Hellpunktdefekt aufweist, indem der Wert der Spannung, die durch den Datentreiber (20) abgetastet wurde, mit einem Referenzwert verglichen wird;

Korrigieren der Datenspannung (Vdata) und der Referenzspannung (Vref), die dem Sub-pixel (SP) von dem angenommen wird, dass es den progressiven Hellpunktdefekt aufweist, zugeführt werden sollen, so dass das Sub-Pixel (SP) in einem Anzeigemodus abgedunkelt wird; und zum

Liefern der korrigierten Werte für die Datenspannung (Vdata) und die Referenzspannung (Vref) an den Datentreiber (20), wobei in einem Anzeigemodus die Ansteuerspannung für den Ansteuertransistor (DT) des Sub-Pixels (SP) von dem angenommen wird, dass es den progressiven Hellpunktdefekt aufweist, so konfiguriert ist, dass sie kleiner als eine Schwellenspannung des Ansteuertransistors (DT) ist.

2. OLED-Anzeigeeinrichtung nach Anspruch 1, wobei der Hellpunktschätzer (50) konfiguriert ist, um den abgetasteten Spannungswert mit dem Schwarzdaten-Wert zu vergleichen, um das Sub-Pixel (SP) als den progressiven Hellpunktdefekt aufweisend einzuschätzen, wenn der abgetastete Spannungswert größer oder gleich dem Schwarzdaten-Wert ist, um zu ermöglichen, dass die Schwarzdaten-Spannung (Vblack) dem Sub-Pixel (SP) zugeführt wird, von dem angenommen wird, dass es den progressiven Hellpunktdefekt aufweist, und das Sub-Pixel (SP) durch Erhöhen der Referenzspannung (Vref) entsprechend dem abgetasteten Spannungswert abzudunkeln.
3. OLED-Anzeigeeinrichtung nach Anspruch 1, ferner umfassend einen Bildprozessor (200), der den Hellpunktschätzer (50) enthält, wobei der Bildprozessor (200) konfiguriert ist, um eine Schwellenspannung des Treibertransistors (DT) durch den Datentreiber (20) abzutasten, um die abgetastete Schwellenspannung mit einer vorbestimmten minimalen Schwellenspannung zu vergleichen, um einen normalen Hellpunktdefekt abzutasten, bei dem die abgetastete Schwellenspannung kleiner ist als die minimale Schwellenspannung, und

das abgetastete Sub-Pixel (SP), das den normalen Hellpunktdefekt aufweist, verdunkelt, indem dem Sub-Pixel (SP) Schwarz-Daten zugeführt werden.

4. OLED-Anzeigeeinrichtung nach Anspruch 3, wobei der Hellpunktschätzer (50) konfiguriert ist, um ein Sub-Pixel (SP) abzuschätzen und abzutasten, von dem angenommen wird, dass es den progressiven Hellpunktdefekt aufweist, wenn eine Ansteuerzeit aufgrund eines Minutenkurzschlusses vergeht, der von Partikeln zwischen einer Versorgungsleitung einer Hochpotential-Spannung und einem Gate-Knoten (N1) des Ansteuertransistors (DT) herrührt.

5. Verfahren zum Ansteuern einer OLED-Anzeigeeinrichtung, umfassend:

Liefern einer aus dem Schwarzdaten-Wert konvertierten Schwarzdaten-Spannung (Vblack) von einem Datentreiber (20) auf einer Datenleitung (DL) über einen ersten Schalttransistor (ST1) an einen ersten Knoten (N1) eines Treibertransistors (DT) eines Sub-pixels (SP) und einer Referenzspannung (Vref) auf einer Referenzleitung (RL) über einen zweiten Schalttransistor (ST2) zu einem zweiten Knoten des Ansteuertransistors (DT) des Sub-Pixels (SP), wodurch dem Treibertransistor (DT) des Sub-Pixels (SP) eine Differenzspannung aus den Schwarz-Daten (Vblack) und der Referenzspannung (Vref) als Sperrspannung zugeführt wird,

Ermöglichen, dass ein Leckstrom gemäß der Sperrspannung des Treibertransistors (DT) während einer vorbestimmten Lichtemissionsperiode zu dem lichtemittierenden Element fließt;

Speichern einer dem Leckstrom gemäß der Sperrspannung des Treibertransistors (DT) entsprechenden Spannung in einem Kondensator (Cref), der mit der Referenzleitung (RL) verbunden ist, und

Abtasten der im Kondensator (Cref) gespeicherten Spannung über die Referenzleitung (RL);

Schätzen, ob ein Sub-Pixel (SP) einen progressiven Hellpunktdefekt aufweist, indem ein Wert der abgetasteten Spannung mit einem Schwarzdaten-Wert verglichen wird; und

Korrigieren der Datenspannung (Vdata) und der Referenzspannung (Vref), die dem Sub-Pixel (SP) zugeführt werden sollen, von dem angenommen wird, dass es den progressiven Hellpunktdefekt aufweist, so dass das Sub-Pixel (SP) in einem Anzeigemodus abgedunkelt wird, wobei die Ansteuerspannung für den Ansteuertransistor (DT) des Sub-Pixels (SP) so konfiguriert ist, dass sie kleiner als eine Schwellenspannung des Ansteuertransistors (DT) ist.

6. Verfahren nach Anspruch 5, wobei das Schätzen umfasst, Vergleichen des abgetasteten Spannungswerts mit dem Schwarzdaten-Wert und Einschätzen des Sub-Pixels (SP) als den progressiven Hellpunktdefekt aufweisend, wenn der abgetastete Spannungswert größer oder gleich dem Schwarzdaten-Wert ist. 5
7. Verfahren nach Anspruch 6, wobei das Speichern umfasst, Liefern der Schwarzdaten-Spannung (Vblack) an den Sub-Pixel (SP), von dem angenommen wird, dass es den progressiven Hellpunktdefekt aufweist, und Einstellen der Referenzspannung (Vref) gemäß der abgetasteten Spannung, um das Sub-Pixel (SP) abzudunkeln. 10 15
8. Verfahren nach Anspruch 7, weiter umfassend vor dem Zuführen der Schwarzdaten-Spannung (Vblack) und der Referenzspannung (Vref); Abtasten einer Schwellenspannung eines jeden Treibertransistors (DT); 20
Vergleichen der abgetasteten Schwellenspannung mit einer vorgegebenen minimalen Schwellenspannung, um einen normalen Hellpunktdefekt abzutasten, bei dem die abgetastete Schwellenspannung kleiner als die minimale Schwellenspannung ist; und Abdunkeln eines Sub-Pixels (SP), das als den normalen Hellpunkt aufweisend abgetastet wurde, durch Zuführen der Schwarzdaten-Spannung (Vblack) zu dem Sub-Pixel (SP). 25 30

Revendications

1. Dispositif d'affichage à diode électroluminescente organique (OLED) comprenant : 35
une pluralité de pixels secondaires (SP), chacun d'eux comprenant :
un élément électroluminescent (OLED) et un transistor de commande (DT) destiné à commander l'élément électroluminescent (OLED), 40
un premier transistor de commutation (ST1) connecté entre une ligne de données (DL) et un premier nœud (N1) du transistor de commande (DT), et 45
un second transistor de commutation (ST2) connecté entre une ligne de référence (RL) et un second nœud (N2) du transistor de commande (DT), la ligne de référence (RL) présentant un condensateur (Cref) connecté à celle-ci ; et 50
un dispositif de commande de données (20) configuré pour fournir une tension de données (Vdata) par l'intermédiaire de la ligne de données (DL), et une tension de référen-

ce (Vref) par l'intermédiaire de la ligne de référence (RL), à chaque pixel secondaire (SP) de la pluralité de pixels secondaires (SP) ;

où, dans un mode détection :

le dispositif de commande de données (20) est configuré pour fournir une tension de données de noir (Vblack), convertie à partir de la valeur de données de noir, par l'intermédiaire du premier transistor de commutation (ST1) au premier nœud (N1), et une tension de référence (Vref) par l'intermédiaire du second transistor de commutation (ST2), au second nœud (N2), en fournissent ainsi au transistor de commande (DT), une différence de tension entre la tension de données de noir (Vblack) et la tension de référence (Vref), en tant que tension de blocage ; et

le condensateur (Cref) connecté à la ligne de référence est configuré pour stocker une tension selon le courant de fuite du transistor de commande (DT) selon la tension de blocage après une période prédéterminée d'émission de la lumière du mode détection au cours de laquelle le courant de fuite, selon la tension de blocage du transistor (DT), circule dans l'élément électroluminescent (OLED) ; et

où le dispositif de commande de données (20), dans le mode détection, est configuré en outre pour détecter, dans le mode détection, par l'intermédiaire de la ligne de référence (RL), une tension stockée dans un condensateur (Cref), qui est connecté à la ligne de référence (RL) ;

caractérisé en ce que le dispositif d'affichage à diode électroluminescente organique, comprend en outre un estimateur de point lumineux (50) configuré pour :

estimer si un pixel secondaire (SP) présente un défaut de point lumineux progressif en comparant la valeur de ladite tension détectée par le dispositif de commande de données (20), à une valeur de référence ;
corriger la tension de données (Vdata) et la tension de référence (Vref) à fournir au pixel secondaire (SP) dont on estime qu'il présente le défaut de point lumineux progressif, de telle sorte que ledit pixel secondaire (SP) soit assombri dans un mode affichage ; et
fournir les valeurs corrigées de la tension de données (Vdata) et de la tension de ré-

- férence (Vref) au dispositif de commande de données (20) où, dans un mode affichage, la tension de commande (Vref) du transistor de commande (DT) du pixel secondaire (SP) dont on estime qu'il présente le défaut de point lumineux progressif, est configurée pour être inférieure à une tension de seuil dudit transistor de commande (DT).
2. Dispositif d'affichage OLED selon la revendication 1, où l'estimateur de point lumineux (50) est configuré pour comparer la valeur de tension détectée à la valeur de données de noir, pour estimer le pixel secondaire (SP) dont on estime qu'il présente le défaut de point lumineux progressif, quand la valeur de tension détectée est égale ou supérieure à la valeur de données de noir, afin de permettre la fourniture de la tension de données de noir (Vblack) au pixel secondaire (SP) dont on estime qu'il présente le défaut de point lumineux progressif, et pour assombrir le pixel secondaire (SP) en augmentant la tension de référence (Vref) selon la valeur de tension détectée.
 3. Dispositif d'affichage OLED selon la revendication 1, comprenant en outre un processeur d'image (200) comprenant l'estimateur de point lumineux (50), où le processeur d'image (200) est configuré pour détecter une tension de seuil du transistor de commande (DT) par l'intermédiaire du dispositif de commande de données (20), pour comparer la tension de seuil détectée à une tension prédéterminée de seuil minimum pour détecter un défaut de point lumineux normal où la tension de seuil détectée est inférieure à la tension de seuil minimum, et assombrit le pixel secondaire (SP) détecté pour présenter le défaut de point lumineux normal en fournissant des données de noir au pixel secondaire (SP).
 4. Dispositif d'affichage OLED selon la revendication 3, où l'estimateur de point lumineux (50) est configuré pour estimer et détecter un pixel secondaire (SP) dont on s'attend à ce qu'il présente le défaut de point lumineux progressif quand un temps de commande passe, en raison d'un micro court-circuit résultant de particules entre une ligne d'alimentation d'une tension à potentiel élevé et un nœud de grille (N1) du transistor de commande (DT).
 5. Procédé de commande d'un dispositif d'affichage OLED comprenant les étapes suivantes :
 - fournir, à partir d'un dispositif de commande de données (20), une tension de données de noir (Vblack), convertie à partir de la valeur de données de noir, sur une ligne de données (DL) par l'intermédiaire d'un premier transistor de commutation (ST1) à premier nœud (N1) d'un transistor de commande (DT) d'un pixel secondaire (SP), et une tension de référence (Vref) sur une ligne de référence (RL) par l'intermédiaire d'un second transistor de commutation (ST2) au second nœud du transistor de commande (DT) du pixel secondaire (SP), en fournissant de ce fait une différence de tension entre la tension de données de noir (Vblack) et la tension de référence (Vref), en tant que tension de blocage, au transistor de commande (DT) du pixel secondaire (SP), permettre à un courant de fuite selon la tension de blocage du transistor de commande (DT) de circuler dans l'élément électroluminescent au cours d'une période prédéterminée d'émission de la lumière ; stocker une tension correspondant au courant de fuite selon la tension de blocage du transistor de commande (DT), dans un condensateur (Cref) connecté à la ligne de référence (RL), et détecter la tension stockée dans le condensateur (Cref) par l'intermédiaire de la ligne de référence (RL) ; estimer si un pixel secondaire (SP) présente un défaut de point lumineux progressif en comparant la valeur de la tension détectée à une valeur de données de noir ; et corriger la tension de données (Vdata) et la tension de référence (Vref) à fournir au pixel secondaire (SP) dont on estime qu'il présente le défaut de point lumineux progressif, de telle sorte que le pixel secondaire (SP) soit assombri dans un mode affichage, où la tension de commande du transistor de commande (DT) du pixel secondaire (SP) est configurée pour être inférieure à une tension de seuil du transistor de commande (DT).
 6. Procédé selon la revendication 5, où l'étape d'estimation comprend l'étape suivante : comparer la valeur de tension détectée à la valeur de données de noir, et estimer le pixel secondaire (SP) dont on estime qu'il présente le défaut de point lumineux progressif lorsque la valeur de tension détectée est égale ou supérieure à la valeur de données de noir.
 7. Procédé selon la revendication 6, où l'étape de stockage comprend les étapes suivantes : fournir la tension de données de noir (Vblack) au pixel secondaire (SP) dont on estime qu'il présente le défaut de point lumineux progressif, et régler la tension de référence (Vref) selon la tension détectée afin d'assombrir le pixel secondaire (SP).
 8. Procédé selon la revendication 7, comprenant en outre, avant l'étape consistant à fournir la tension de

données de noir (V_{black}) et la tension de référence (V_{ref}), les étapes suivantes :

détecter une tension de seuil de chaque transistor de commande (DT) ; 5
comparer la tension de seuil détectée à une tension de seuil minimum prédéterminée afin de détecter un défaut de point lumineux normal où la tension de seuil détectée est inférieure à la tension de seuil minimum ; et 10
assombrir un pixel secondaire (SP) dont on estime qu'il présente le défaut de point lumineux progressif normal en fournissant la tension de données de noir (V_{black}) au pixel secondaire (SP). 15

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FIG. 1

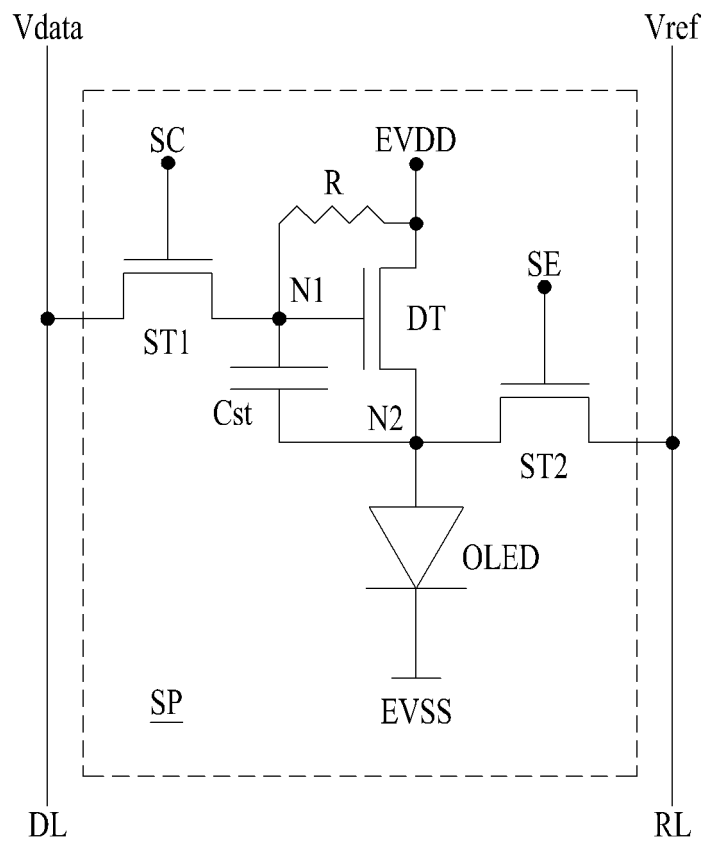


FIG. 2

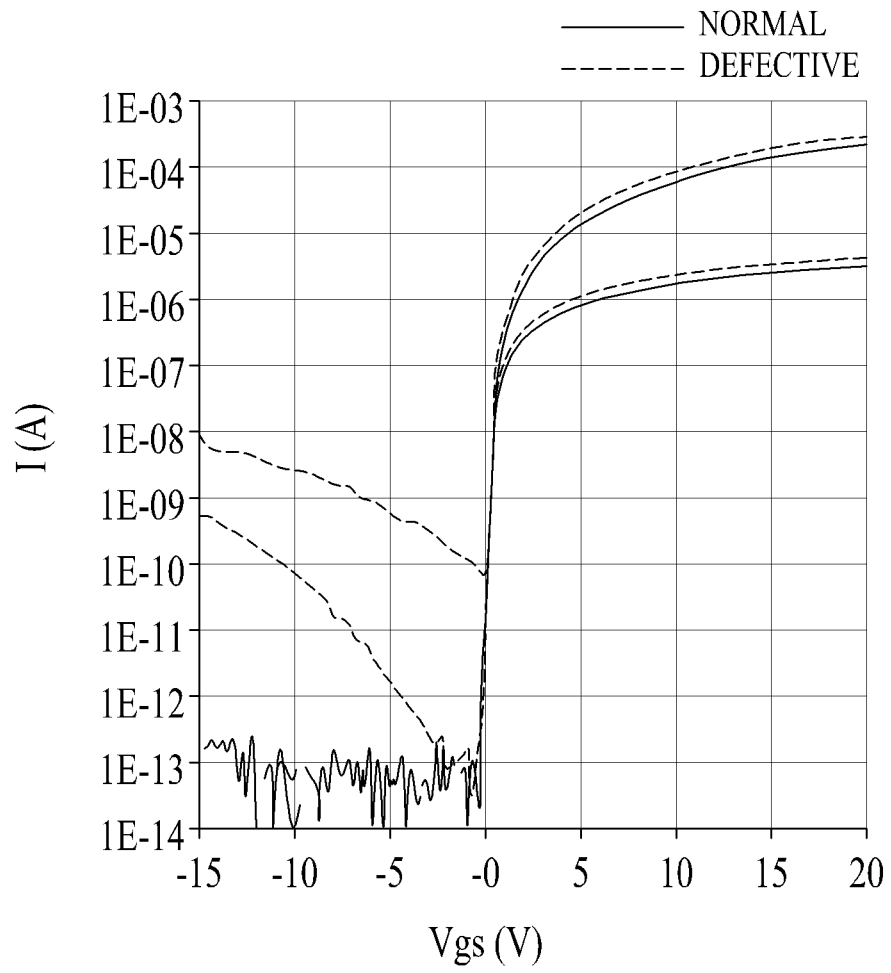


FIG. 3

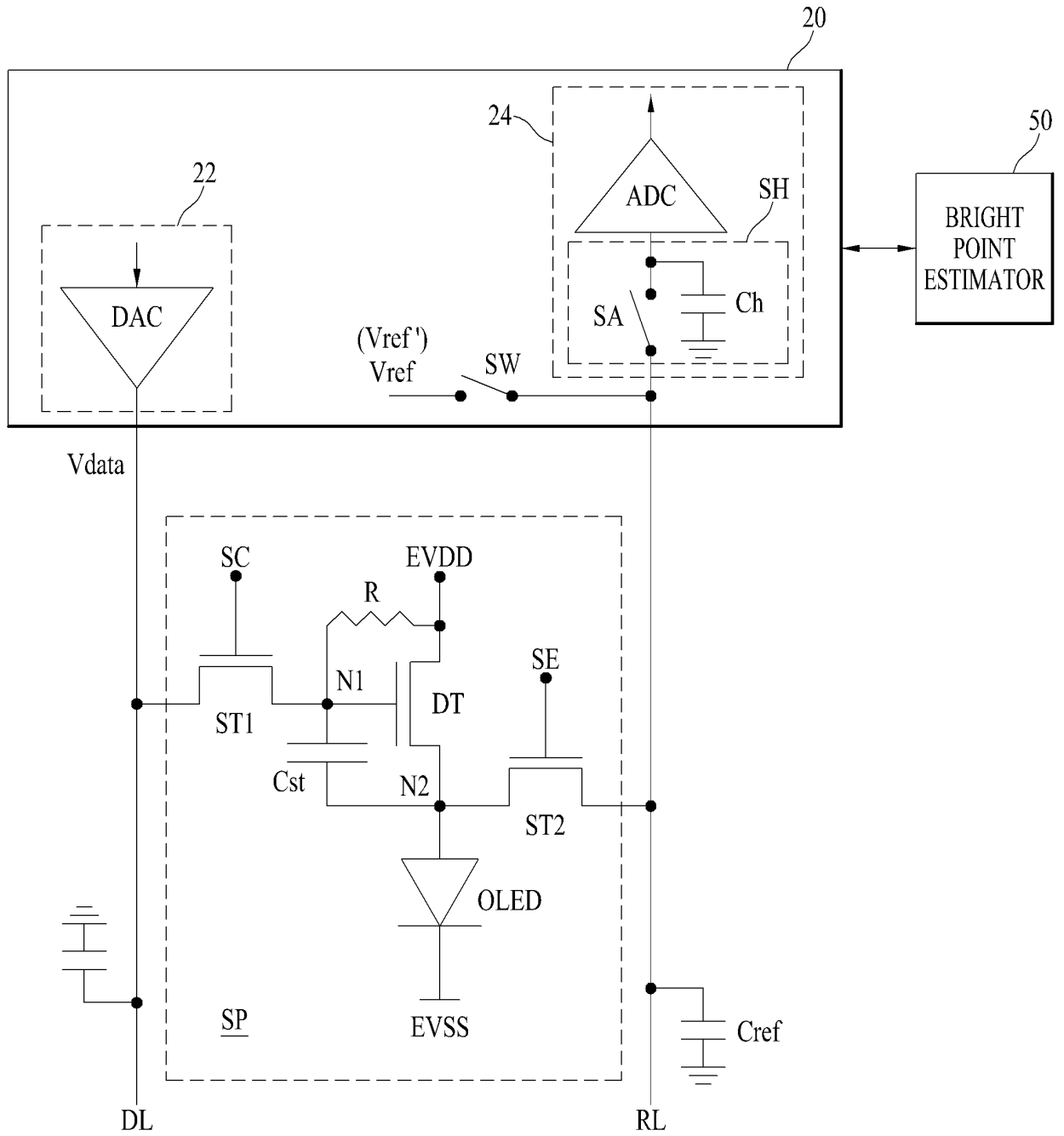


FIG. 4

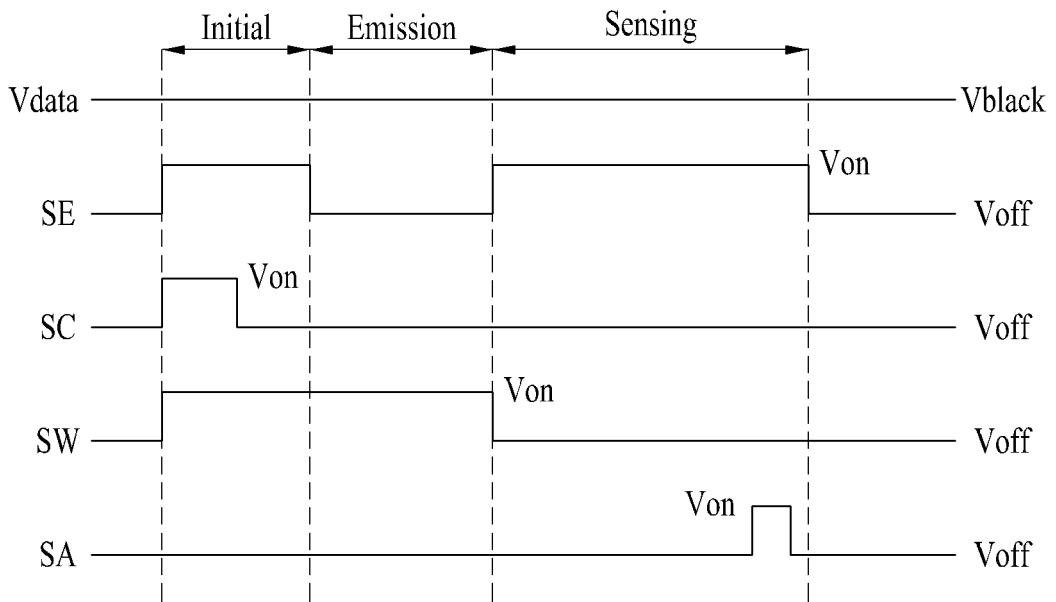


FIG. 5A

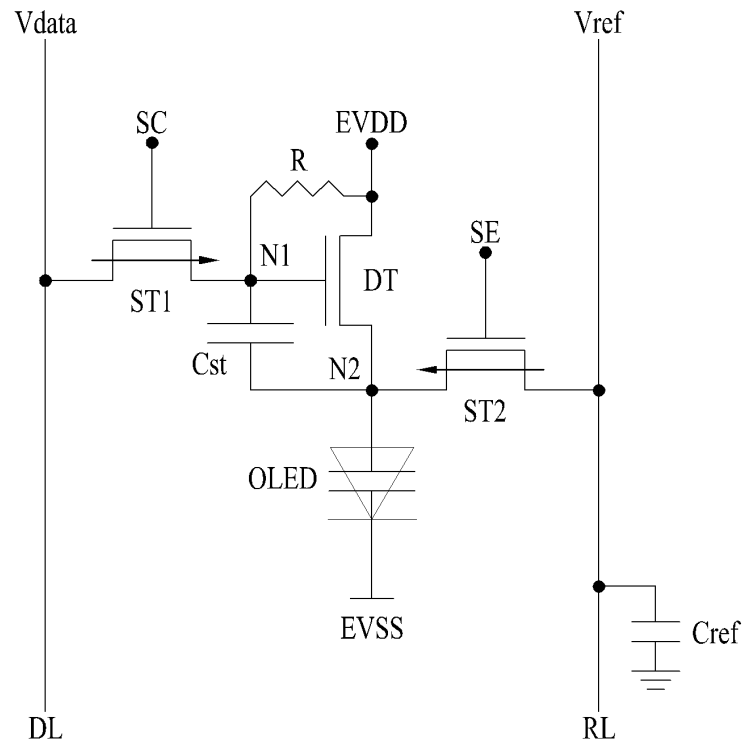


FIG. 5B

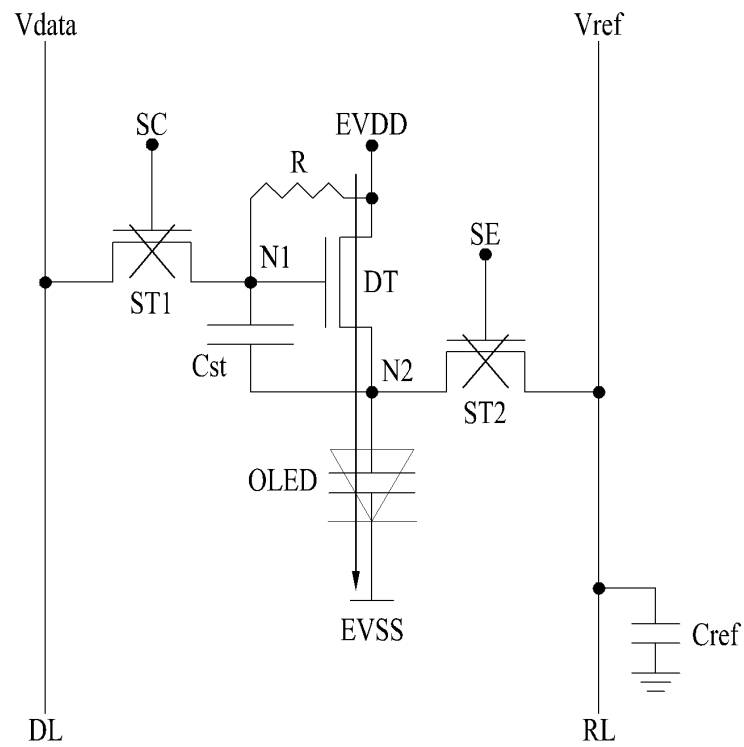


FIG. 5C

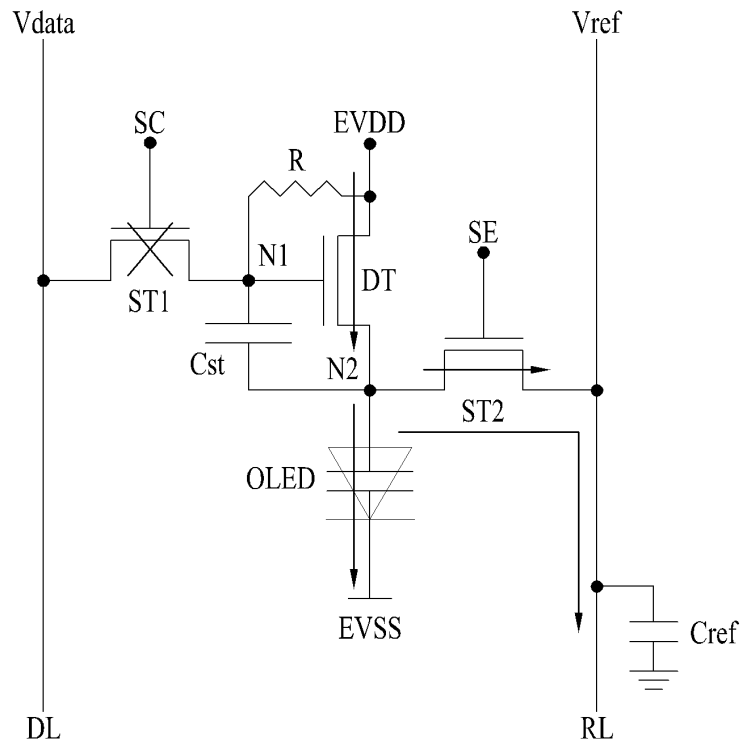


FIG. 5D

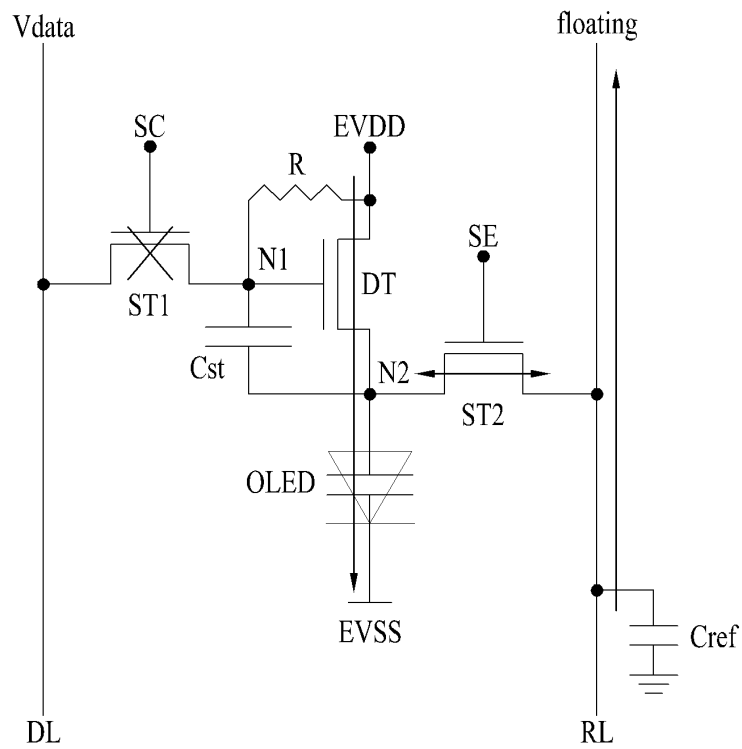


FIG. 6A

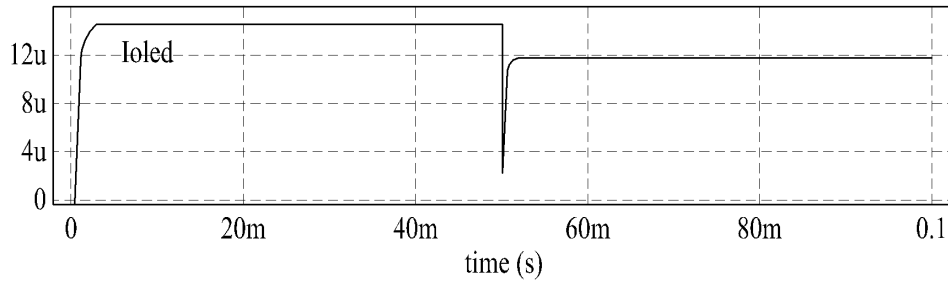
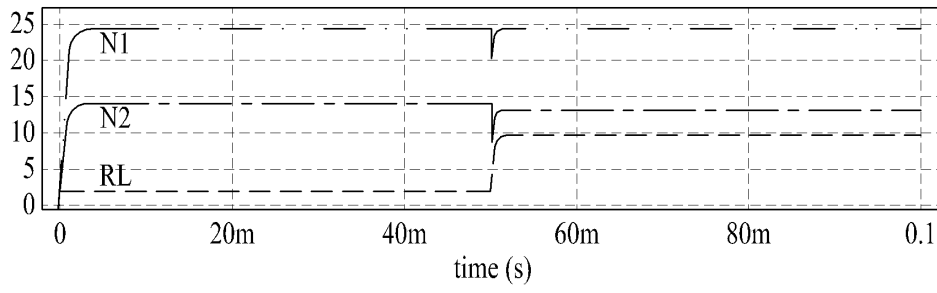


FIG. 6B

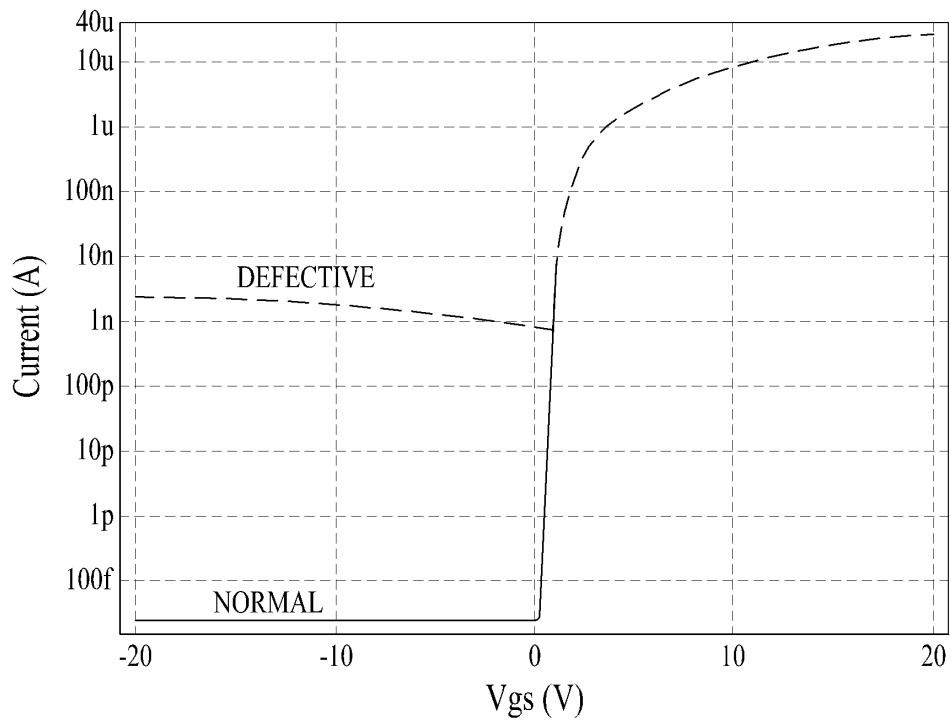


FIG. 7A

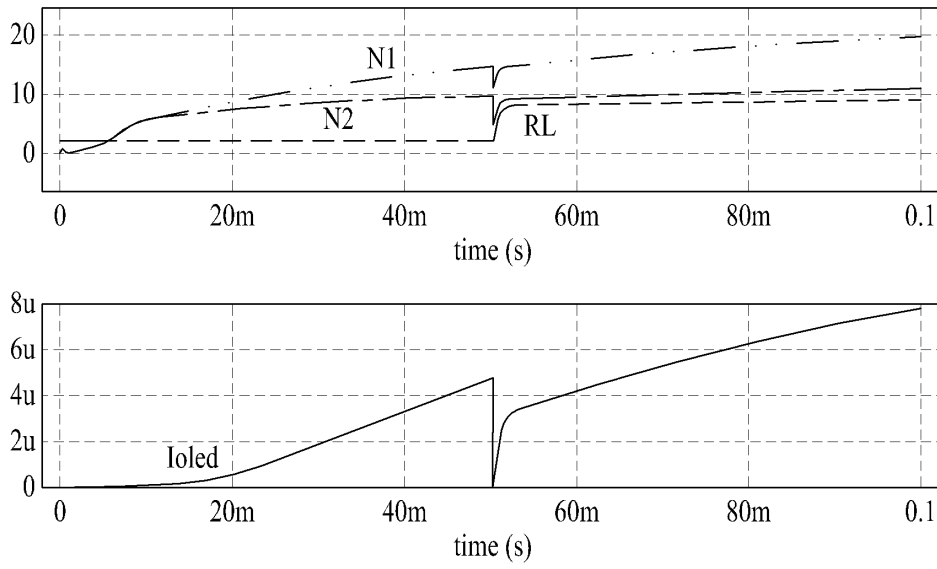


FIG. 7B

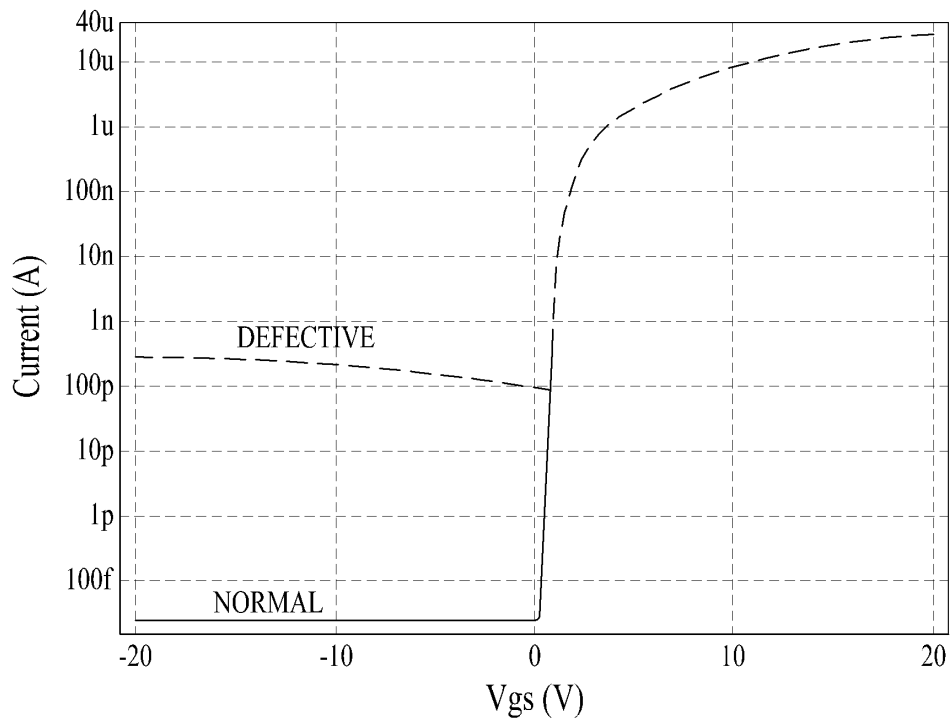


FIG. 8A

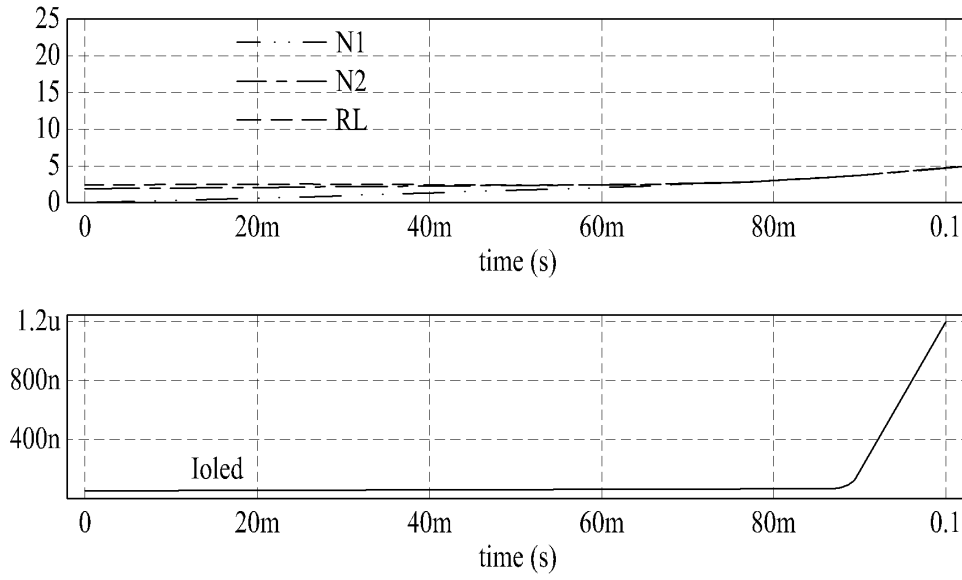


FIG. 8B

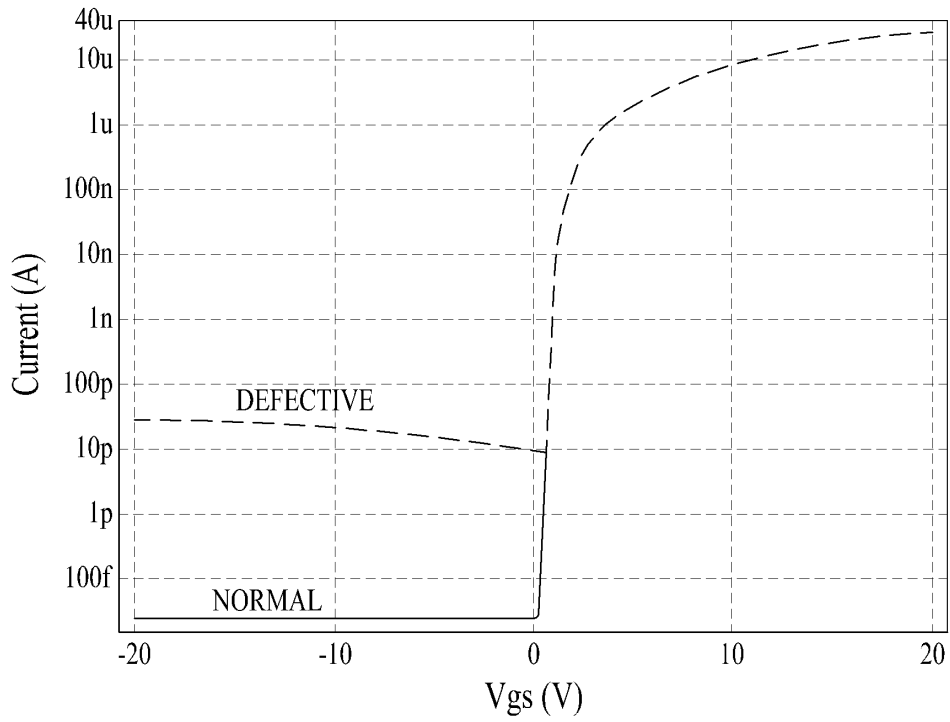


FIG. 9

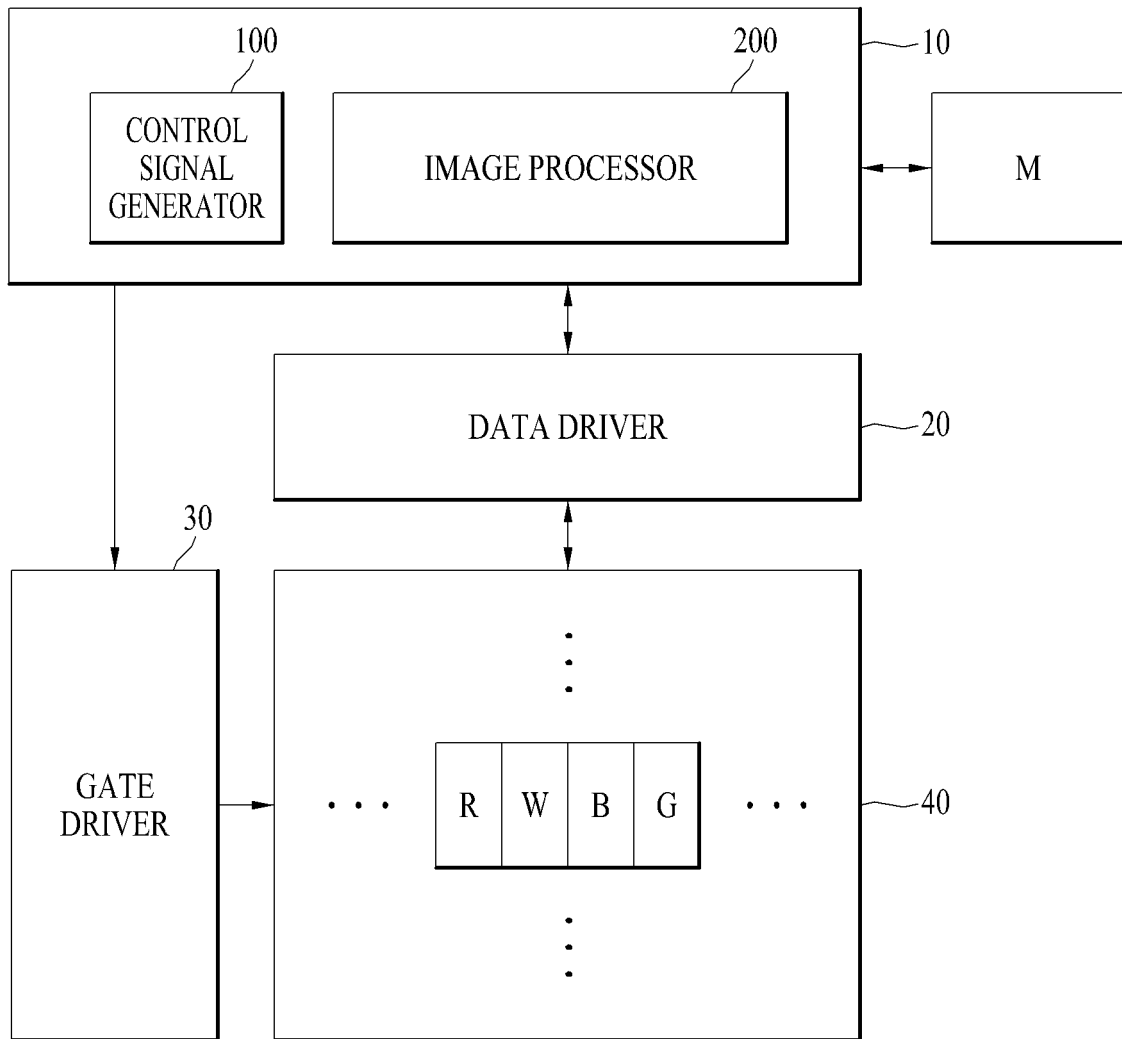
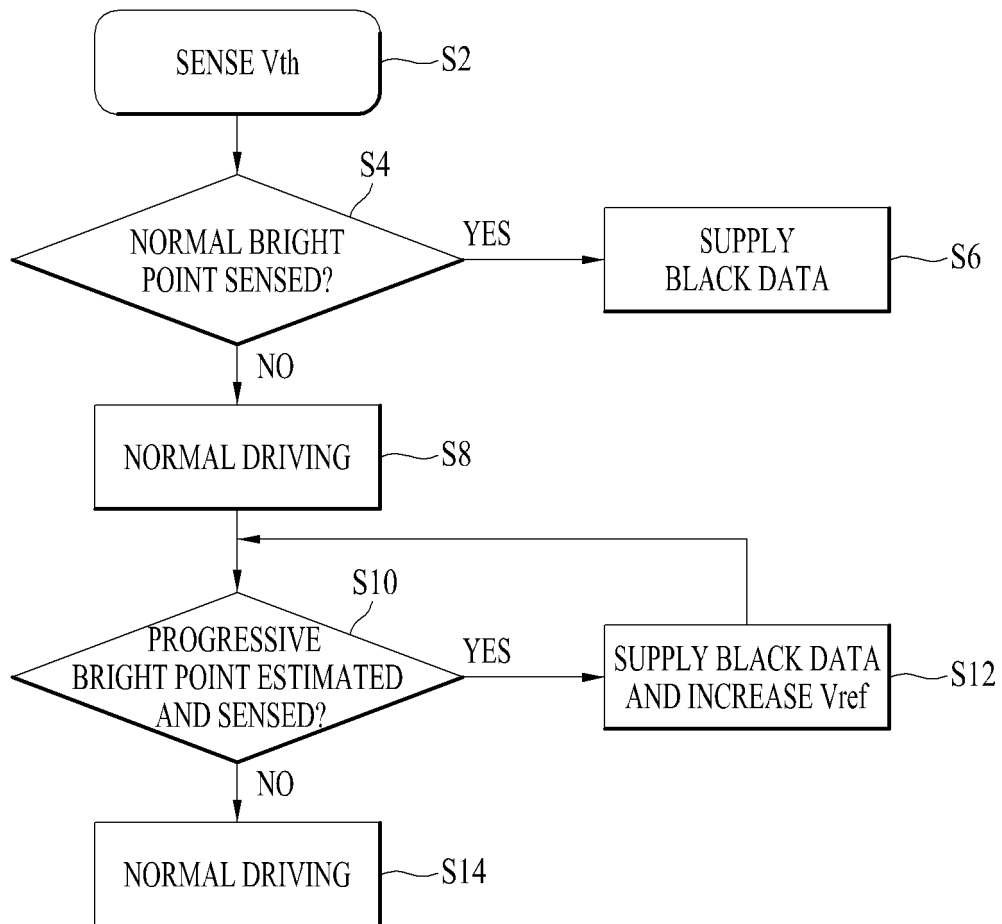


FIG. 10



REFERENCES CITED IN THE DESCRIPTION

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- US 2013050292 A1 [0009]
- US 2007159742 A1 [0010]

专利名称(译)	具有有机发光二极管的显示装置及其控制方法		
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申请(专利权)人(译)	LG DISPLAY CO. , LTD.		
当前申请(专利权)人(译)	LG DISPLAY CO. , LTD.		
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发明人	PARK, KWANG-MO CHOI, SOO-HONG LEE, YOON-JU JEON, KWANG-HUN		
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优先权	1020140149901 2014-10-31 KR		
其他公开文献	EP3016095A1		
外部链接	Espacenet		

摘要(译)

公开了一种能够感测和校正渐进式亮点缺陷的OLED显示装置及其驱动方法。OLED显示装置包括数据驱动器(20)，该数据驱动器用于向驱动晶体管(DT)提供截止驱动电压，以驱动每个子像素(SP)中的发光元件，并感测与泄漏电流对应的电压。驱动晶体管(DT)和亮点估计器(50)，该亮点估计器通过将通过数据驱动器(DT)感测到的电压值与参考值进行比较，从而估计子像素(SP)的逐行亮点，并且使校正估计具有渐进亮点的子像素(SP)。

FIG. 1

